

A Preliminary Result on Characteristics of Temporal Column Abundances of CO₂ and CH₄ from the Ground-based FTS at Anmyeondo, Korea during 2015

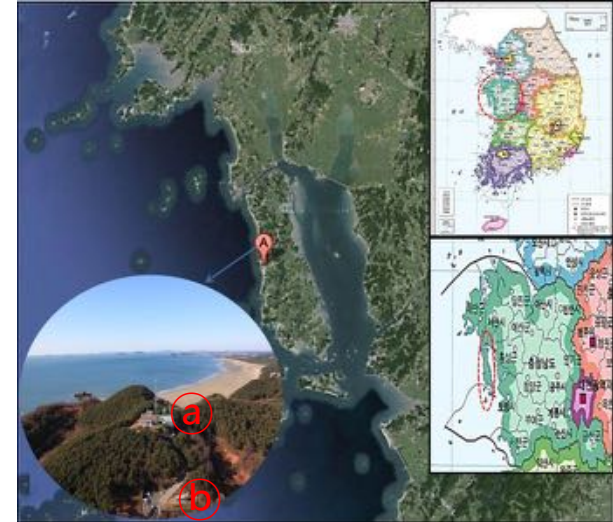
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Site Description

- ❖ Anmyeondo is operational TCCON site located at mid-west Korea
- ❖ Lat/Lon/Alt: 36°32N / 126°19E / 30 m a.s.l.
- ❖ A: WMO Regional GAW station
- ❖ B: FTS site
- ❖ IFS-125HR / A547N solar tracker / Camtracker
- ❖ InGaAs, Si diode / CaF2 / NIR source
- ❖ OASIS (Operational Automatic System for Intensity of Sunray)



Improvement of Spectral Measurement

- ◆ Development of Operational Automatic System for Intensity of Sunray (OASIS)
 - Photo-electronic sensor detects the number of photons in solar beam.
 - Aperture controls the diameter of solar beam according to photons.
 - A maximum solar energy can be given in the detection range of the FTS.



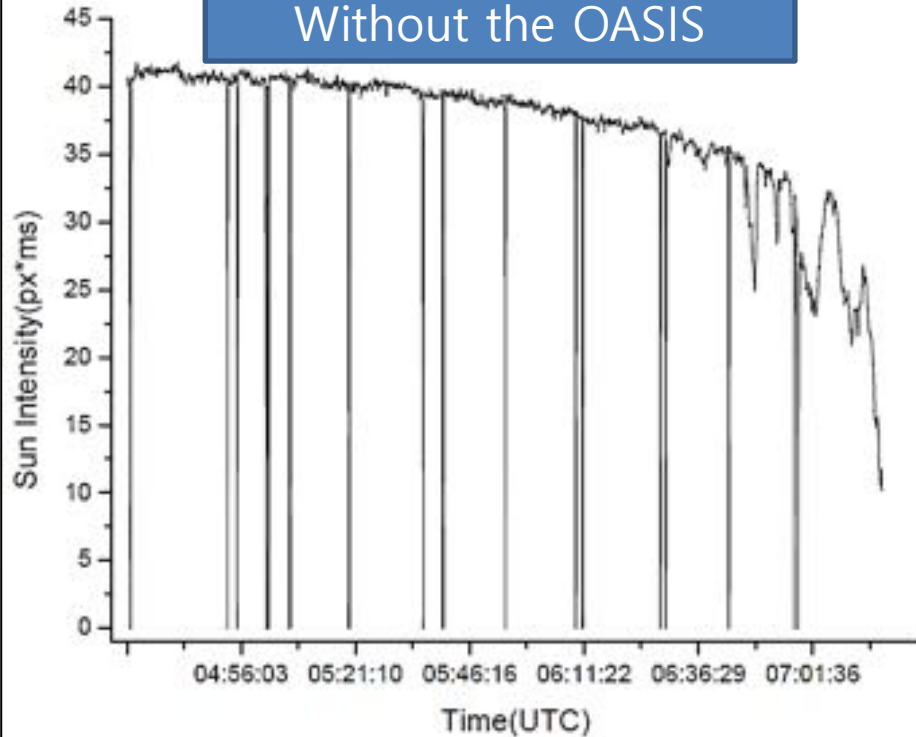
**Aperture
Control Unit**



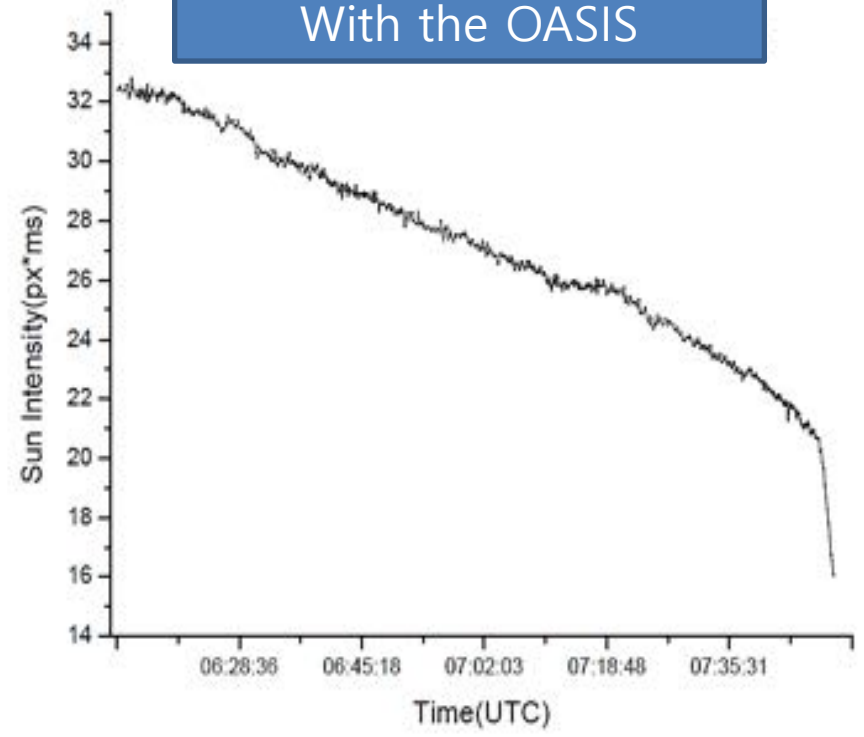
Sensor

OASIS Effect

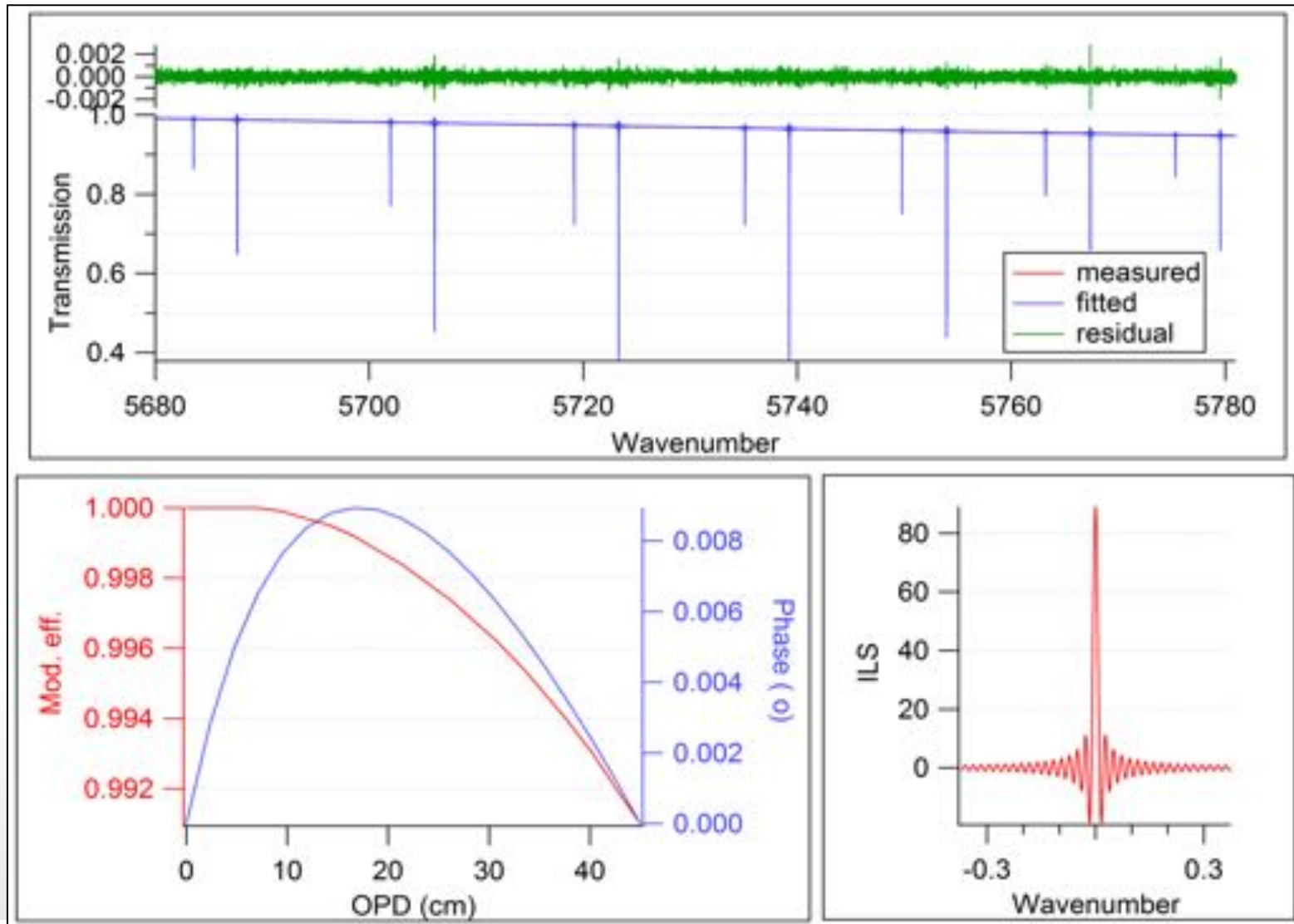
Without the OASIS



With the OASIS

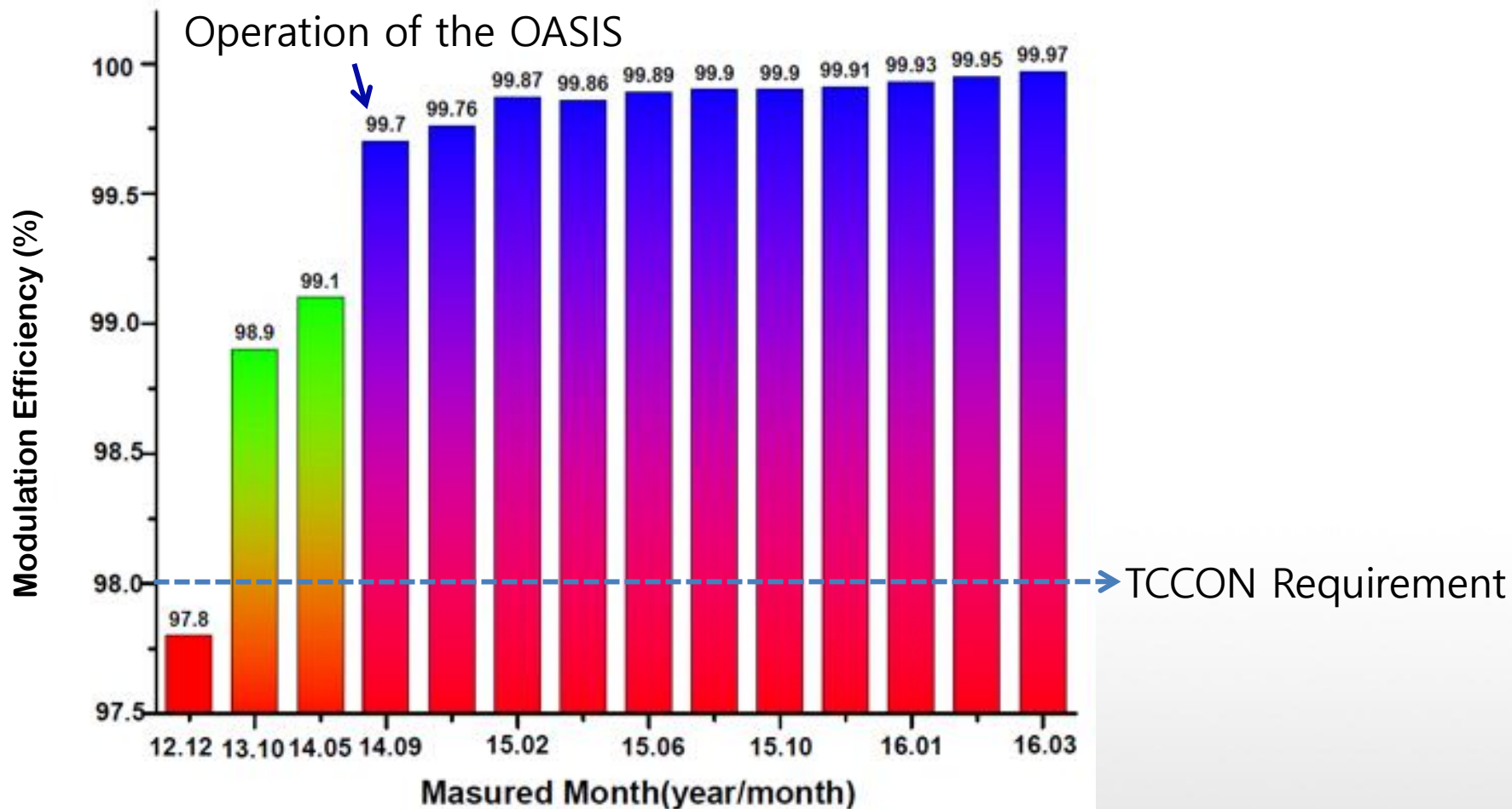


Accuracy of Measured Spectrum



Modulation Efficiency

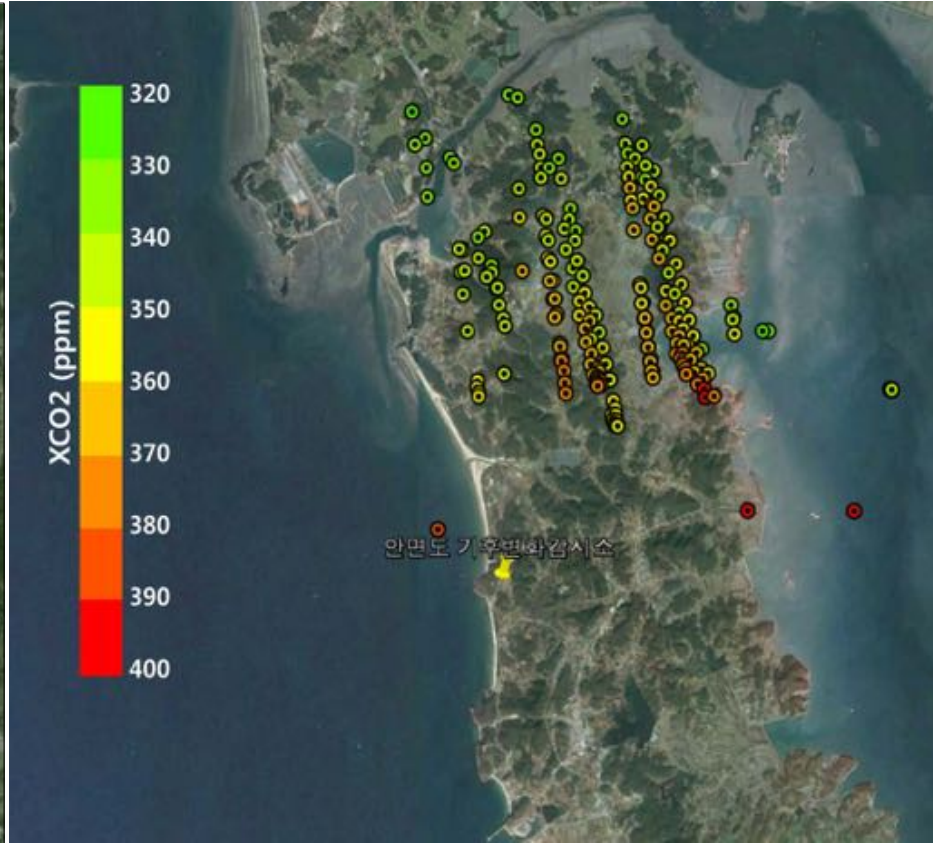
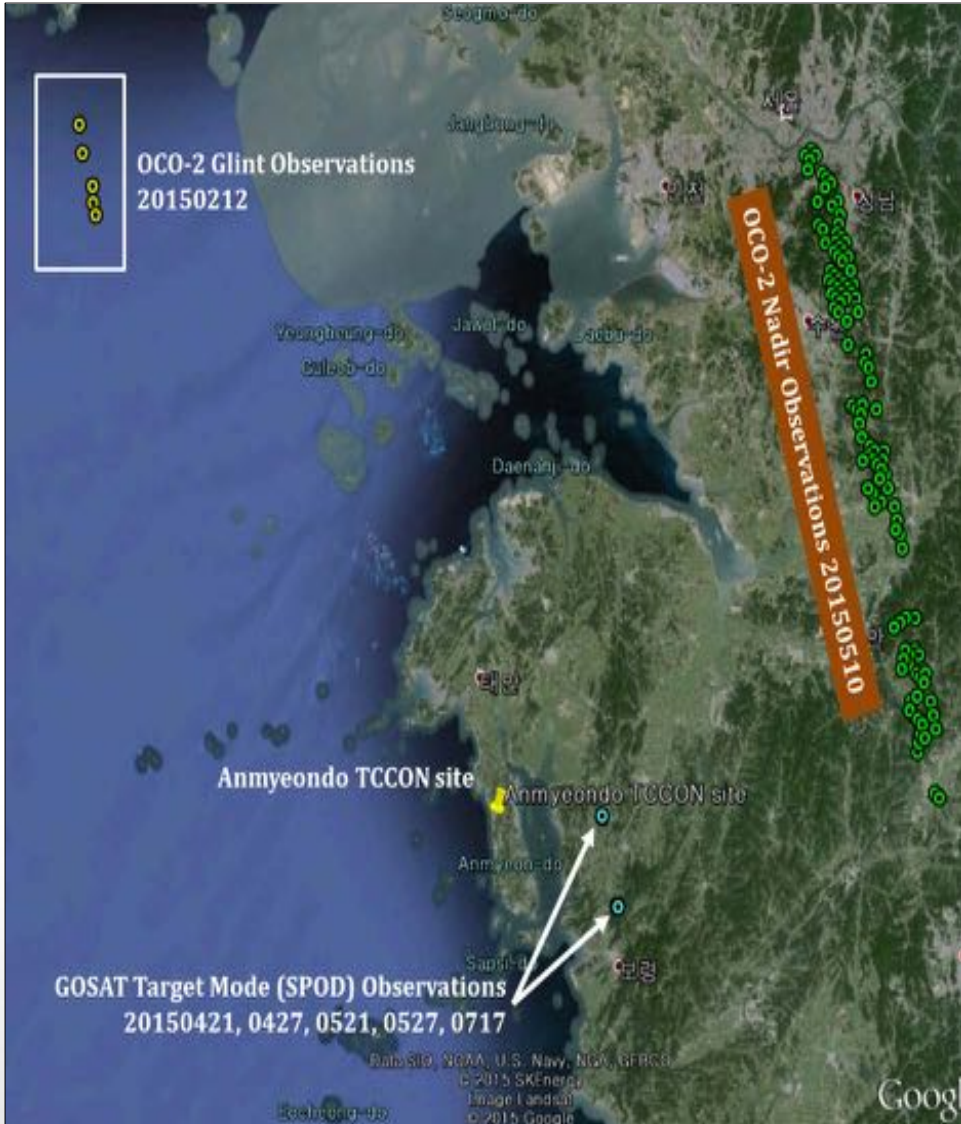
◆ Monthly Modulation Efficiency (45 cm OPD)



Instrument Configurations



	FTS(IFS-125HR)	GOSAT-FTS	OCO-2 (grating)
Band	9000~16,000 cm^{-1} (Si Diode Detector)	12,900~13,200 cm^{-1} (Si Diode Detector)	12,953~13,210 cm^{-1} (HgCdTe Detector)
	3,800~12,800 cm^{-1} (InGaAs Detector)	5,800~6,400 cm^{-1} (InGaAs Detector)	6,172~6,289 cm^{-1} (HgCdTe Detector)
		4,800~5,200 cm^{-1} (InGaAs Detector)	4,807~4,901 cm^{-1} (HgCdTe Detector)
Spec. Res.	0.2 cm^{-1}	0.2 cm^{-1}	0.3 cm^{-1}
Time. Res.	Every 2~3 min.	Every 3 days	Every 16 days



Data

◆ Insitu Observation Data

- Data/Period: Hourly-averaged CO₂ & CH₄ / 2015.1.~12.
- Site/Instrument: KGAWC / CRDS (Cavity Ring-Down Spectroscopy)

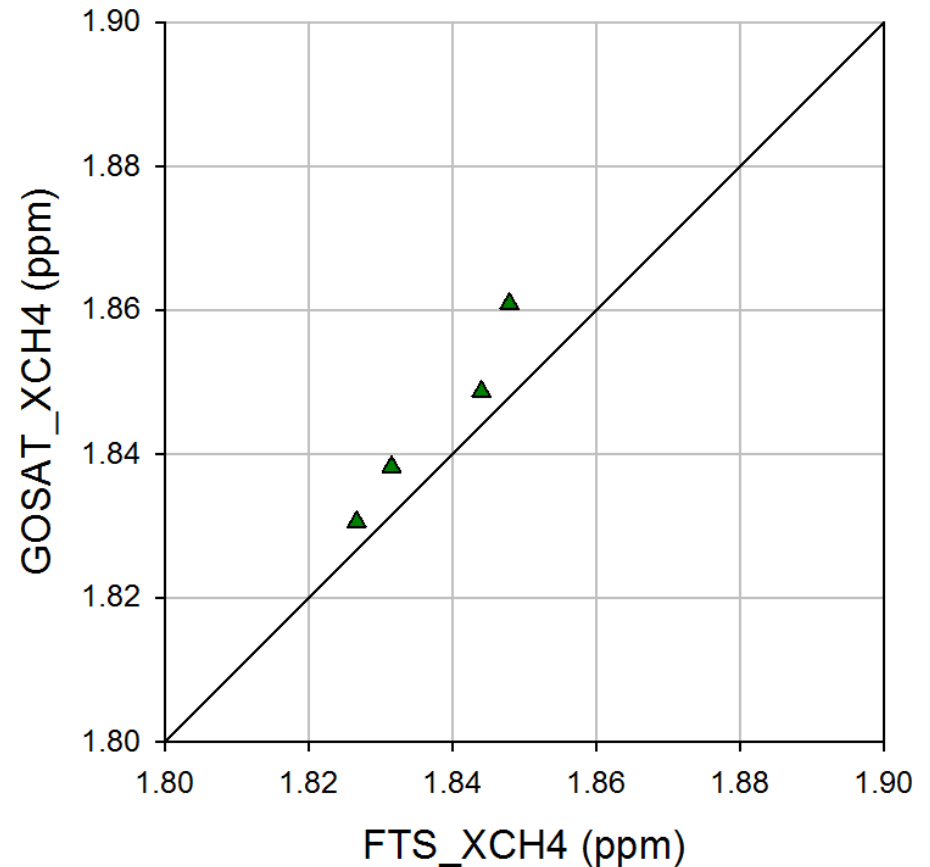
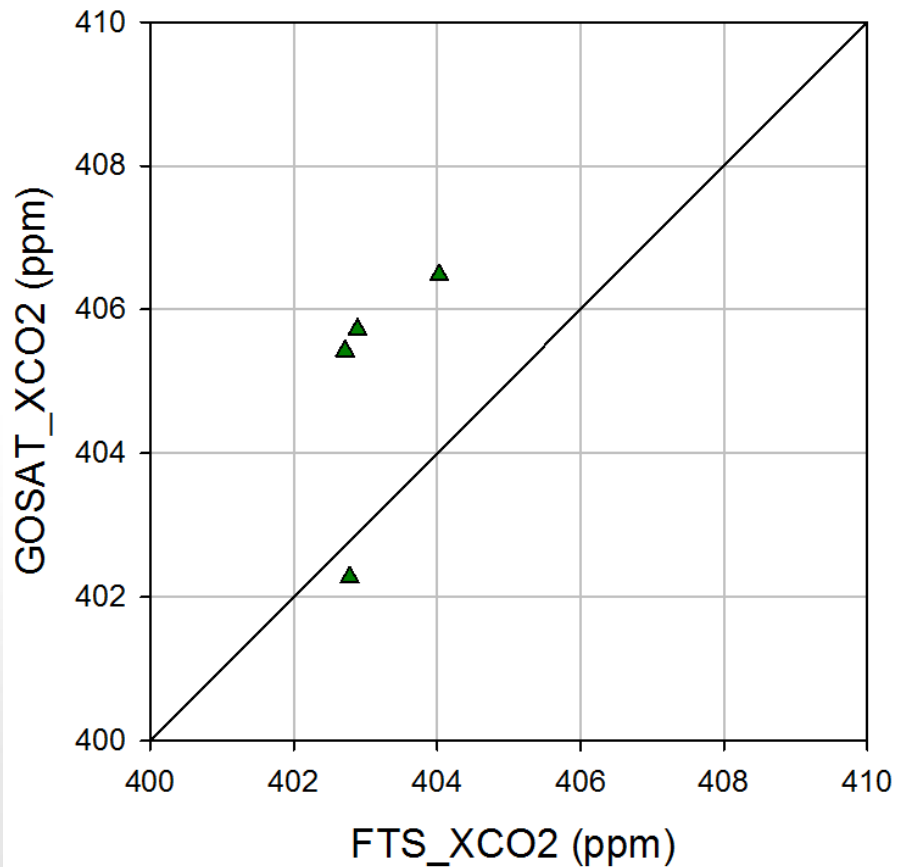
◆ Ground-based FT-IR Measurements & Retrievals

- Data/Period: Hourly-averaged XCO₂ & XCH₄ / 2015.2.~9.
- Site/Instrument: KGAWC / IFS-125HR

◆ Satellite-based FT-IR Measurements & Retrievals

- Data/Period: Spatially-averaged XCO₂ & XCH₄ around 1300LST / 2015.1.~12.
- Area/Satellite: KGAWC ±0.5 Lat & Lon / OCO-2, GOSAT

	XCO2 Dif.	XCH4 Dif.
2015. 4. 21.	2.449	0.013
2015. 4. 27.	2.707	0.004
2015. 5. 21.	2.830	0.005
2015. 5. 27.	-0.507	0.007
Average	1.870	0.007



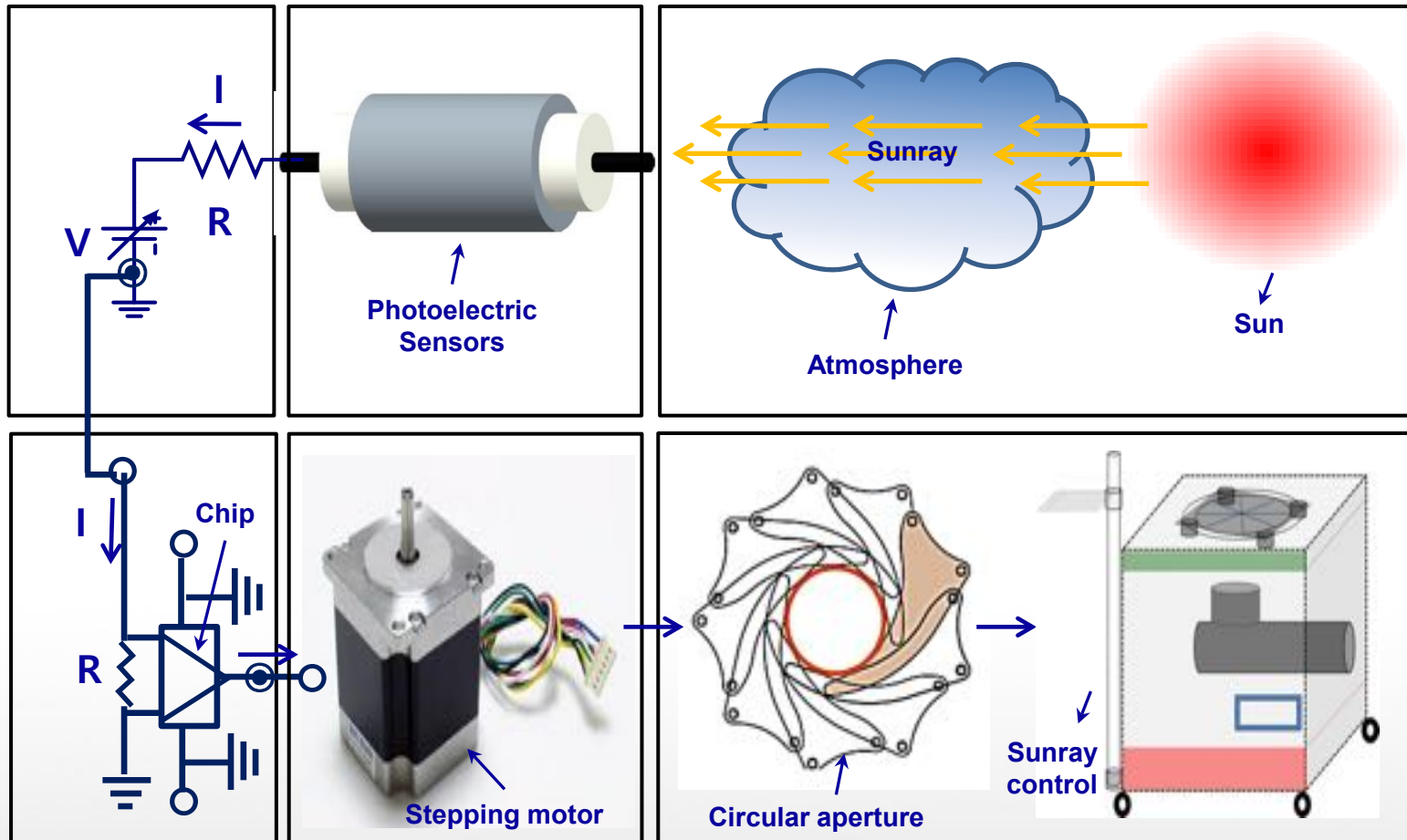
Summary

- ◆ Ground-based FT-IR measurements show significant stability with high accuracy and reliability.
 - after consistently maximizing the incoming solar intensity by using the OASIS
 - in the accuracy of spectral measurement over 99.9% since Feb 2015
- ◆ The features of seasonal variability of CO₂ & CH₄ are well captured
 - in both insitu and ground-based FT-IR measurements
- ◆ Retrieved XCO₂ & XCH₄ from the ground-based FT-IR represent reliable annual cycles.
 - with high concentration in winter-spring season and low in summer season
- ◆ Limited CO₂ & CH₄ retrievals have obtained from the satellite-based FT-IR.
 - due to the spectrum contamination resulted from clouds, aerosols and interferences of other atmospheric species
 - Validation results against the G-B FT-IR are likely to be reasonable.

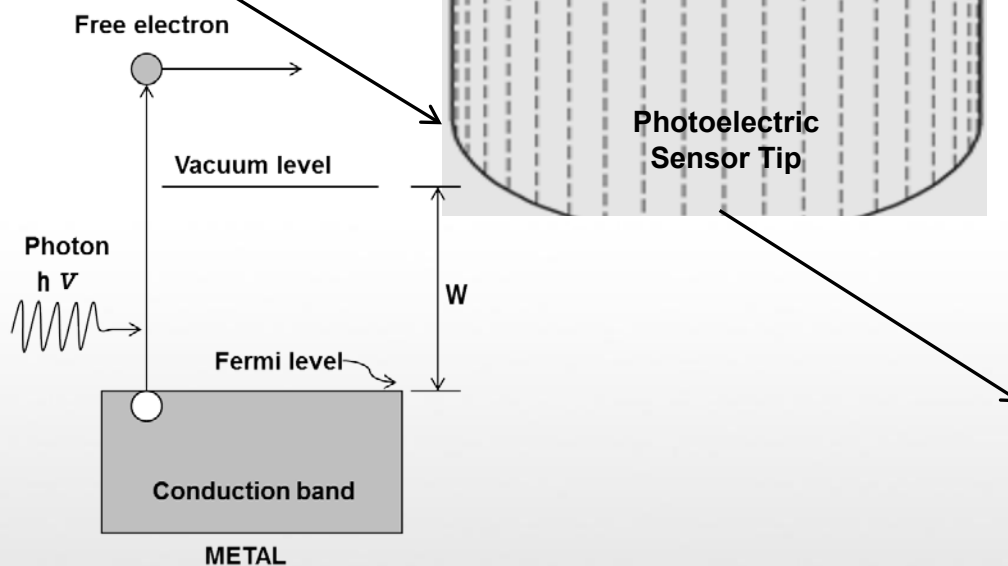
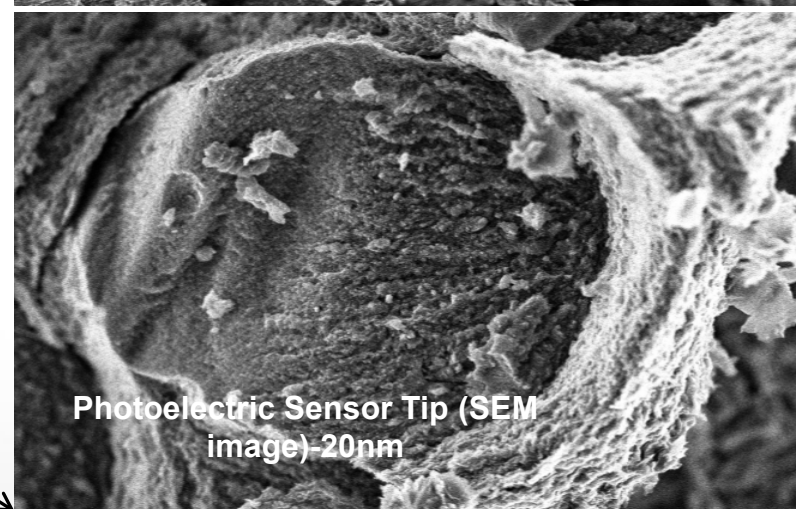
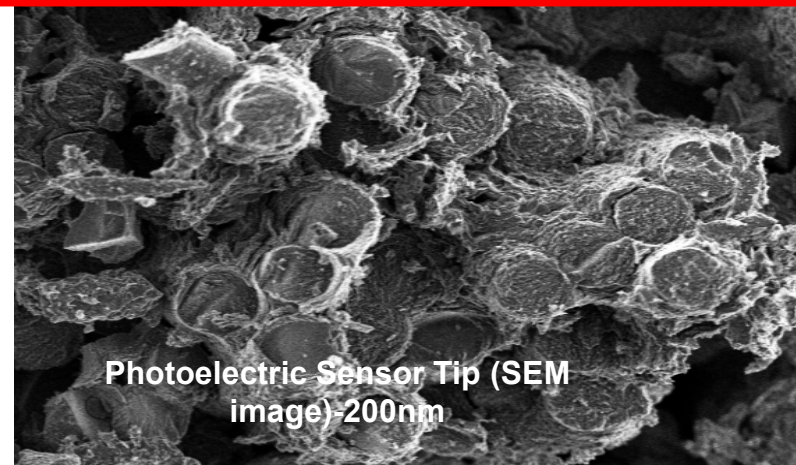
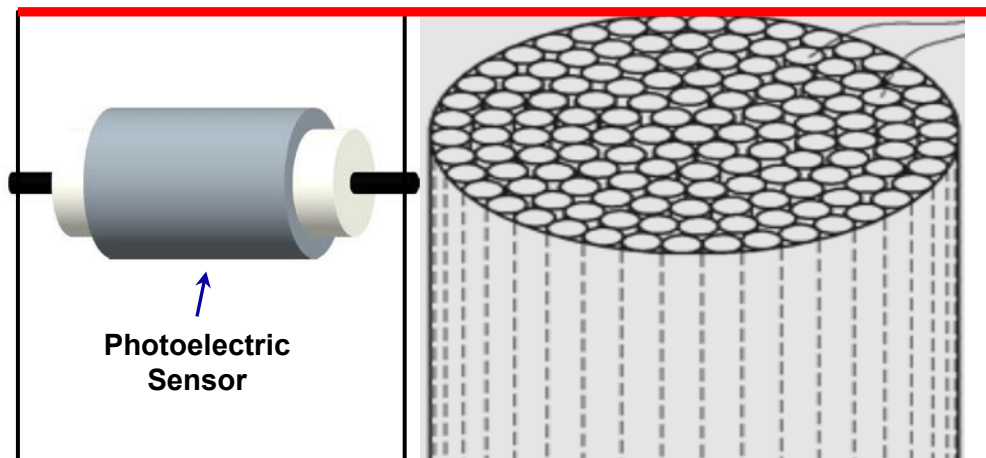
Thank you

☐ FTS Consolidated system (2015년 TCCON 발표내용)

No> Phase 1. OASIS (Operational Automatic System for Intensity of Sunray)

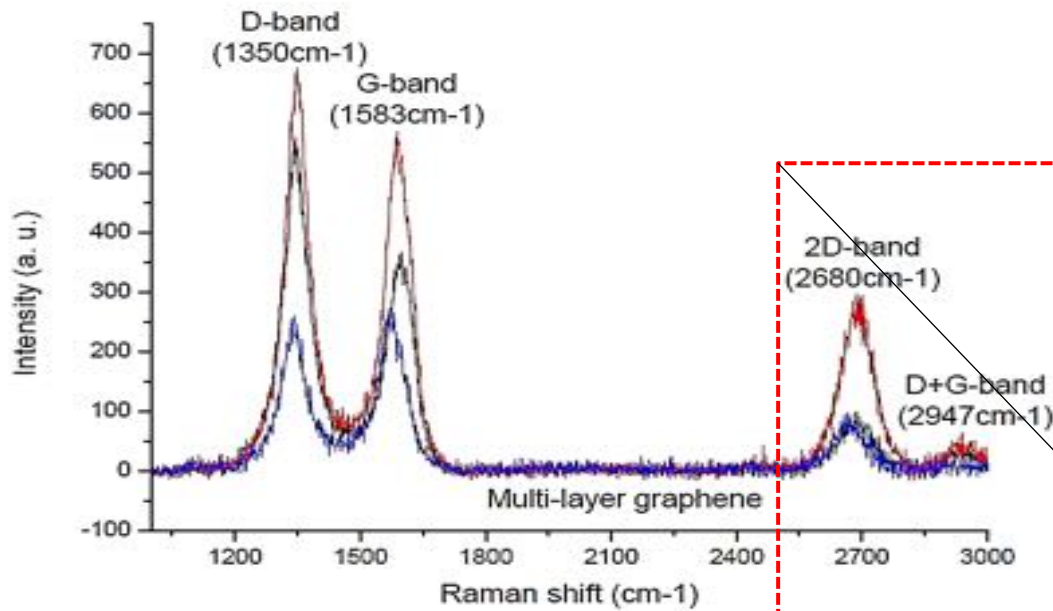


1. Photoelectric Sensor

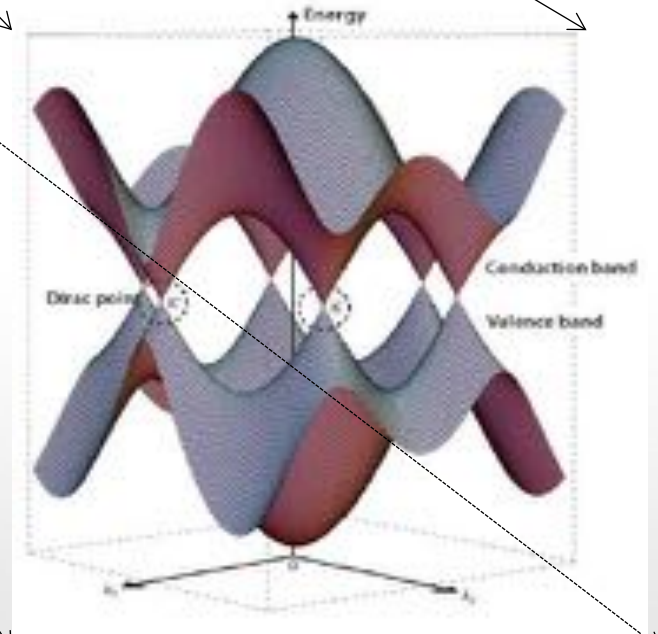


Sensor Tip Price: 1,259,23 \$

2. Physical Properties of the Photoelectric Sensor

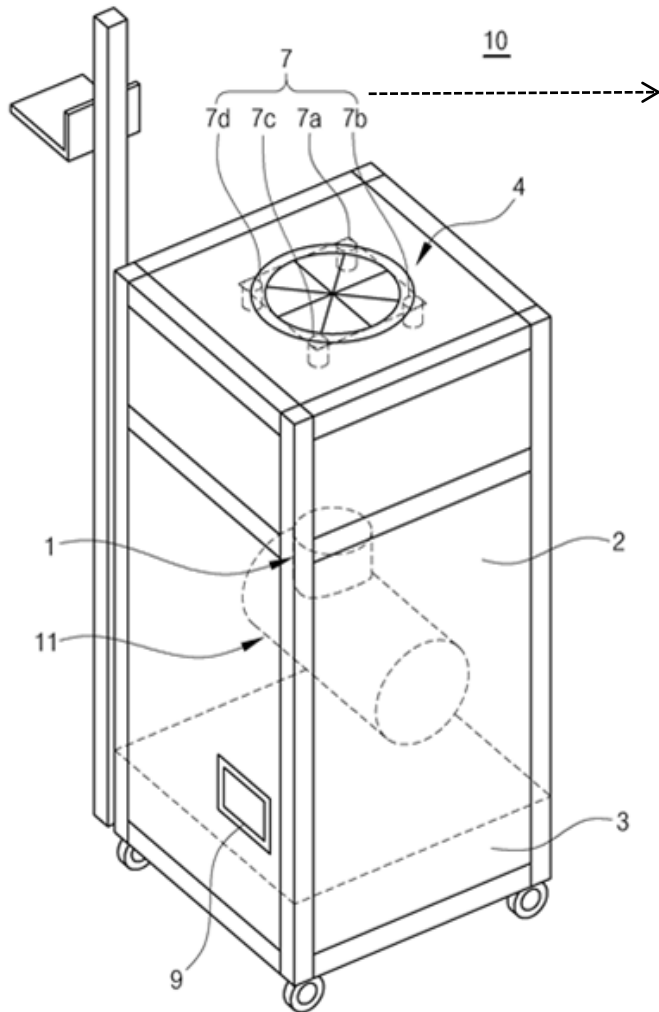


Main Bond Structure of the Graphene Tip

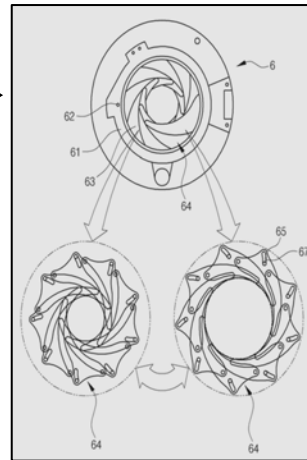


Dirac Point----->Transfer Port

3. OASIS Configuration and Price

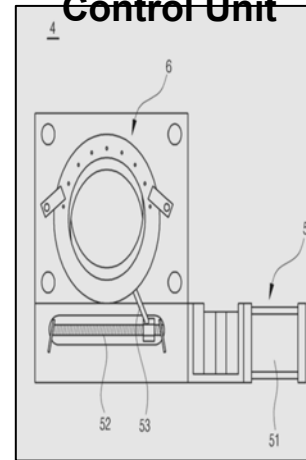


Aperture



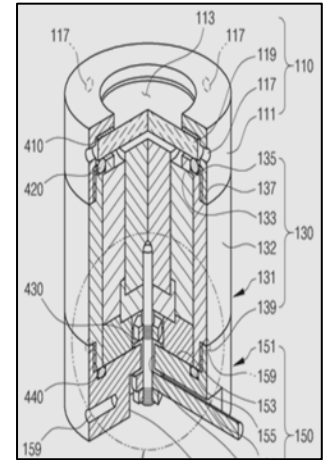
335,80 \$

Aperture Control Unit



923,44 \$

Sensor



3,357,96 \$



OASIS



Aperture Control Unit



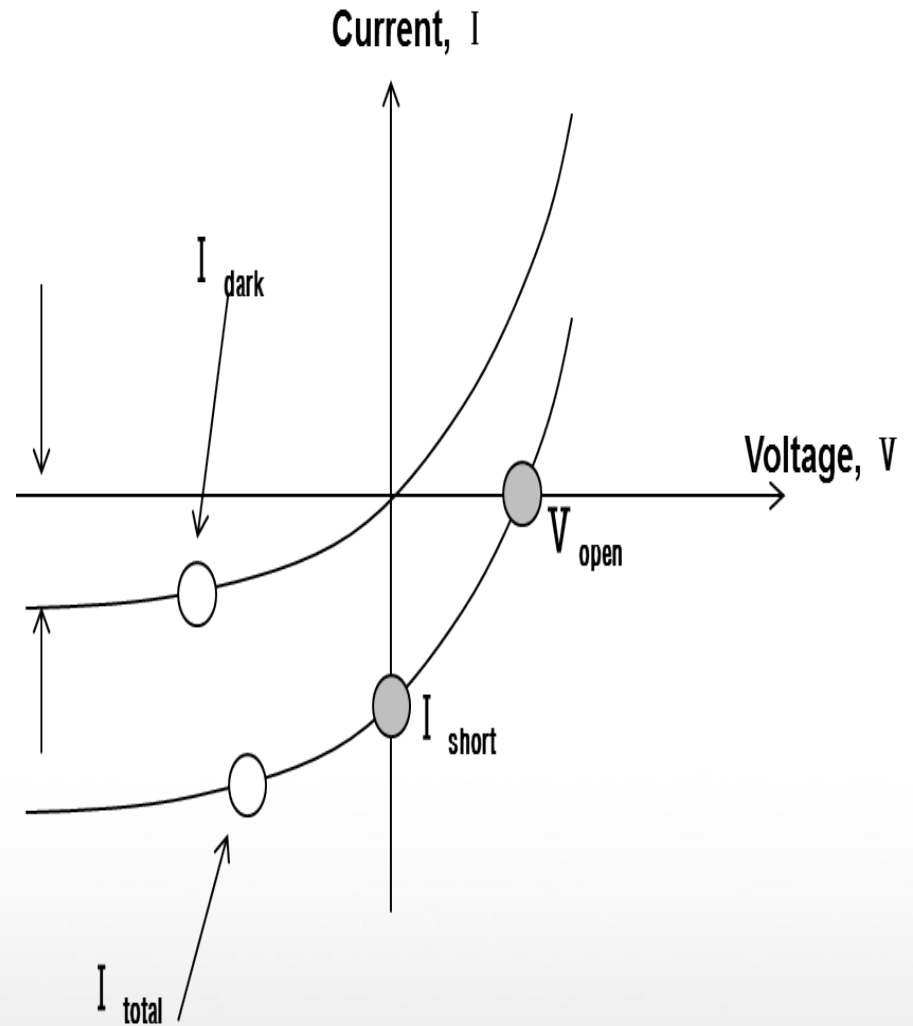
Sensor

OASIS: 20,987,24 \$ (total)

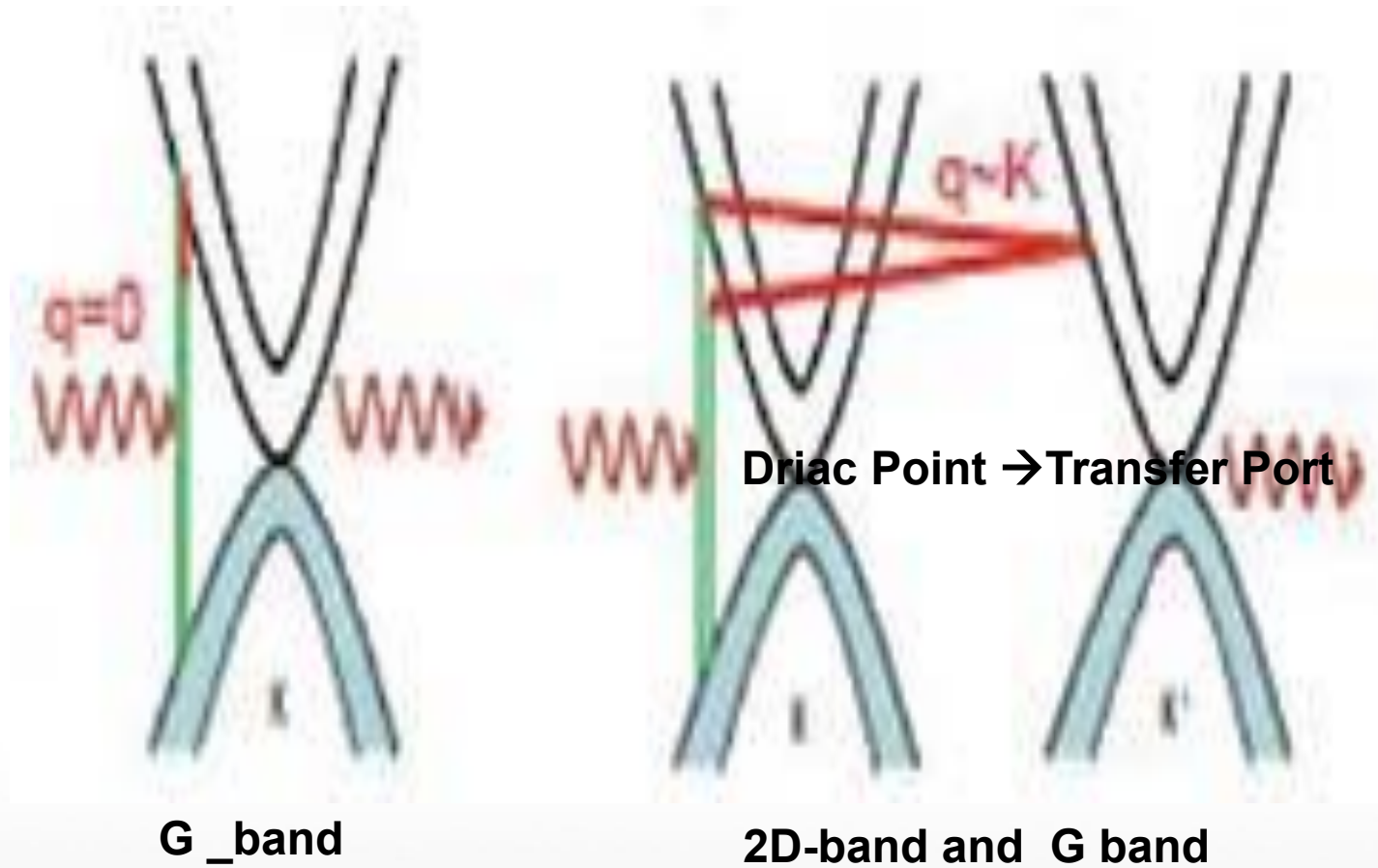
1. Photoelectric Sensor(보충 자료)

전기적,기계적,열 특성 요약

성질	특성	5D_CF C	비고
전자적 성질	전하 이동도 ($\text{cm}^2/\text{v}\cdot\text{se c}$)	200000	구리(Cu)의 150배
	허용 전류 밀도 (A/cm^2)	5×10^8	구리(Cu)의 100배
	면 저항 (Ω)	<50	구리(Cu)의 35% 미만
	밴드 갭 (eV)	0~0.3	실리콘이 1.11
기계적 성질	강도 (Gpa)	1100	구리(Cu)의 200배
	유연성/신축성	원 면적의 20%	타 금속 물질은 1~5% 미만
열적 성질	열전도율 (W/mK)	5000	CNT의 1.5배



2. Physical Properties of the Photoelectric Sensor (보충 자료)



3. OASIS Configuration and Price (보충자료)

Phase 1. Application and Verification of OASIS

